

ABSTRACT

The implications of electro-osmosis with interfacial slip on electrohydrodynamic transport in microchannels having complex (yet symmetric) cross sectional shapes, by employing a generic semianalytical approach, been presented in this poster. This study is motivated by the fact that in reality, the cross sectional shapes of microchannels may often deviate from circular or rectangular ones, primarily as an artifact of the underlying fabrication process. We devise approximate also an technique of flow rate prediction under these conditions, using a combined consideration electroosmotic slip (under thin electrical double layer limits) and Navier slip conditions (originating out of confinement induced hydrophobic interactions) at the fluid-solid interface. We further (A) Potential distribution: assess the effectiveness of the approximate solutions in perspective of the exact solutions, as a parametric function of the relative thickness of the electrical double layer. We illustrate the underlying consequences through examples of elliptic, polygonal, point star-shaped and annular microchannel sectional cross shapes.

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hydrodynamics intrinsically coupled

Poisson equationIonic charge density
$$\nabla^2 \psi = -\frac{\rho_e}{\varepsilon}$$
 $\rho_e = ez(n^+ - n^-)$

$$\nabla^2 \psi = \frac{2n_0 ez}{\varepsilon} \sinh\left(\frac{ez\psi}{k_B T}\right) \implies \psi(n) = \frac{4k_B T}{ez} t$$



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Title